Low-temperature thermal expansion and magnetostriction of YbRh$_2$(Si$_{1-x}$Ge$_x$)$_2$ ($x = 0$ and 0.05)


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Abstract

We report a comparative study of the low-temperature thermal expansion and magnetostriction of the non-Fermi liquid (NFL) system YbRh$_2$(Si$_{1-x}$Ge$_x$)$_2$ ($x = 0$ and nominally 0.05). The undoped compound ($x = 0$) shows a sharp phase transition anomaly, related to antiferromagnetic ordering at $T_N = 70$ mK, that is suppressed by a small critical field $B_c = 0.06$ T ($B \perp c$). By contrast, very tiny anomalies at $T_N = (20 \pm 5)$ mK and $B_c = (0.027 \pm 0.005)$ T are observed in the $x = 0.05$ system. The NFL behavior above $T_N$ is not affected by the Ge substitution.

The tetragonal heavy fermion system YbRh$_2$Si$_2$ is located very close to an antiferromagnetic (AF) quantum critical point (QCP). At $B = 0$ it shows pronounced non-Fermi liquid (NFL) behavior, i.e. $C/T \propto -\log(T)$ from 10 K down to 0.3 K, below which it diverges stronger than logarithmic [1]. Well below the AF phase transition from 10 K down to 0 K the system enters a Landau Fermi liquid state with a very heavy quasiparticle mass [2]. From both, the magnetic entropy at $T_N$ [2] and $\mu$SR experiments [3] a very small value of about $10^{-2} \mu_B$/Yb for the ordered moment in the AF state is deduced. The application of pressure to YbRh$_2$Si$_2$ increases $T_N$ [5] as expected, because the ionic volume of the magnetic 4f$^{13}$ Yb$^{3+}$ configuration is smaller than that of the non-magnetic 4f$^{14}$ Yb$^{3+}$ one. Expanding the crystal lattice by randomly substituting Ge for the smaller isoelectric Si atoms allows one to reach the zero-field QCP. Below, we report a comparative study of low-temperature thermal expansion and magnetostriction measurements on pure ($x = 0$) and Ge-doped (nominal concentration: $x = 0.05$) YbRh$_2$(Si$_{1-x}$Ge$_x$)$_2$.

Single crystalline platelets with residual resistivities of 1 $\mu\Omega$ cm ($x = 0$) [2] and 5 $\mu\Omega$ cm ($x = 0.05$) [4] were grown from In flux. The $T_N$ vs. pressure diagram of the Ge-doped system matches perfectly with that found for pure YbRh$_2$Si$_2$ if the pressure axis is shifted by $-0.2$ GPa [5]. This reveals an effective Ge-content of 0.02$\pm$0.004 in agreement with the microprobe analysis [6]. The large difference between nominal and effective Ge-content is due to the fact, that Ge dissolves better than Si in the In-flux. The thermal expansion coefficient $\alpha$ is defined as $L^{-1} dL/dT$, where $L$ denotes the sample length. For temperatures between 50 mK and 6 K, a high-resolution capacitive dilatometer of pure silver was used. The low-temperature measurements including the magnetostriction were performed in a CuBe dilatometer. Above 100 mK, we observe for both systems a negative $\alpha(T)$ with a moderate anisotropy $\alpha_{\perp} \approx 1.5 \alpha_{||}$ (Fig. 1). No significant difference between the two systems is found. The pronounced NFL effects visible in $\alpha/T$ vs. $T$ are discussed in Ref. [7]. At lower temperatures, the pure compound shows a sharp phase transition at $T_N = 70$ mK that has disappeared for the $x = 0.05$ system (inset Fig. 1). For the latter the onset of the very weak phase transition observed recently in specific-heat measurements at $T_N = (20 \pm 5)$ mK [6], becomes visible only below about 25 mK.

It has been shown recently, that the AF order in YbRh$_2$Si$_2$ is suppressed by critical magnetic fields $B_c$ of

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0.06 T (0.66 T) applied perpendicular (parallel) to the c-axis [2]. The isothermal magnetostriction $D_L = L(B_c)$ for the pure compound shows a clear kink at $B_c$; indicative of a second-order phase transition (Fig. 2). The negative slope of the magnetostriction for $B > B_c$ results from the magnetic polarization of the Yb$^{3+}$ moments [8]. For the $x = 0.05$ system we observe much smaller changes in $\Delta L/L$ (in order to reduce the noise, several independent measurements have been averaged). This might be related to different in-plane orientations of the two samples, and/or to the effect of the Ge-substitution. A kink, indicative for $B_c$, is visible at $(0.027 \pm 0.005)$ T. A similar value for the critical field in the Ge-doped system has been deduced from specific heat measurements [6].

In summary, the volume expansion produced by a tiny substitution of Si by Ge in YbRh$_2$(Si$_{1-x}$Ge$_x$)$_2$

reduces $T_N$ and $B_c$ to about 20 mK and 25 mT for (nominal) $x = 0.05$. Thus in this system, NFL behavior can be studied extremely close to a zero-field QCP [6,7].

References